

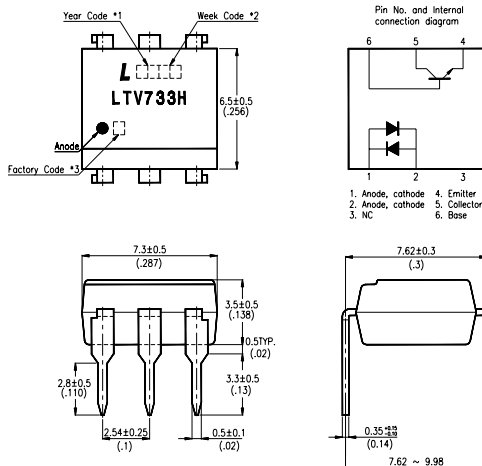
Features

- Directly connectable to TTL
- AC input response
- High input current(I_F : MAX. 150mA)
- High input-output isolation voltage
(Viso = 5,000Vrms)
- Low collector dark current
(I_{CEO} : MAX. 10^{-7} A at $V_{CE} = 20V$)
- Current transfer ratio
(CTR : MIN. 20% at $I_F = \pm 100mA$, $V_{CE} = 2V$)
- UL approved (No. E113898)
- CSA approved (No. CA91533-1)
- FIMKO approved (No. 203512)
- NEMKO approved (No. P98102534)
- DEMKO approved (No. 308184)
- SEMKO approved (No. 9844179/01-02)
- VDE approved (No. 094722)
- Options Available :
 - Leads with 0.4" (10.16mm) Spacing (M Type)
 - Lead Bends for Surface Mounting (S Type)
 - Tape and Reel of Type I for SMD (Add "-TA" Suffix)
 - Tape and Reel of Type II for SMD (Add "-TA1" Suffix)
 - VDE 0884 Approvals (Add "-V" Suffix)

Applications

1. Telephone sets
2. System appliances, measuring instruments
3. Signal transmission between circuits of different potentials and impedances

Package Dimensions



NOTES :

1. Year date code.
2. 2-digit work week.
3. Factory code shall be marked.
(Z : Taiwan, Y : Thailand).
4. All dimensions are in millimeters (inches).
5. Tolerance is $\pm 0.25mm$ (.010") unless otherwise noted.
6. Specifications are subject to change without notice.

Ordering Information

Part Number	Package	Safety Standard Approval	Application part number
LTV-733H LTV-733HM LTV-733HS LTV-733HS-TA LTV-733HS-TA1	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)	• UL approved • CSA approved • FIMKO approved • NEMKO approved • DEMKO approved • SEMKO approved	LTV - 733H
LTV733H-V LTV733HM-V LTV733HS-V LTV733HSTA-V LTV733HSTA1-V	6-pin DIP 6-pin (leads with 0.4" spacing) 6-pin (lead bends for surface mount) 6-pin (tape and reel packaging of type I) 6-pin (tape and reel packaging of type II)	• VDE approved	LTV - 733H

Ratings and Characteristics

Absolute Maximum Ratings

(Ta=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward Current	I _F	± 150	mA
	Power Dissipation	P	230	mW
Output	Collector-Emitter Voltage	V _{CEO}	35	V
	Emitter-Collector Voltage	V _{ECO}	6	V
	Collector-Base Voltage	V _{CBO}	35	V
	Emitter-Base Voltage	V _{EBO}	6	V
	Collector Current	I _C	80	mA
	Collector Power Dissipation	P _C	160	mW
Total Power Dissipation		P _{tot}	320	mW
*1. Isolation Voltage		V _{iso}	5,000	V _{rms}
Operating Temperature		T _{opr}	-30~+100	°C
Storage Temperature		T _{stg}	-55~+125	°C
*2. Soldering Temperature		T _{sol}	260	°C

*1. AC for 1 minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

(1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.

(2) The isolation voltage tester with zero-cross circuit shall be used.

(3) The waveform of applied voltage shall be a sine wave.

*2. For 10 seconds

Electrical / Optical Characteristics

(Ta=25°C)

Parameter		Symbol	Min.	Typ.	Max.	Unit	Conditions
Input	Forward Voltage	V _F	—	1.4	1.7	V	I _F = ± 100mA
	Reverse Current	C _t	—	50	400	pF	V = 0, f = 1KHz
Output	Collector Dark Current	I _{CEO}	—	—	100	nA	V _{CE} = 20V, I _F = 0
	Collector-Emitter Breakdown Voltage	BV _{CEO}	35	—	—	V	I _C = 0.1mA I _F = 0
	Emitter-Collector Breakdown Voltage	BV _{ECO}	6	—	—	V	I _E = 10 μA I _F = 0
Transfer Characteristics	Collector Current	I _C	20	—	80	mA	I _F = ± 100mA
	* Current Transfer Ratio	CTR	20	—	80	%	V _{CE} = 2V
	Collector-emitter Saturation Voltage	V _{CE(sat)}	—	0.1	0.2	V	I _F = ± 100mA I _C = 1mA
	Isolation Resistance	R _{iso}	5 × 10 ¹⁰	1 × 10 ¹¹	—	Ω	DC500V 40~60%R.H.
	Floating Capacitance	C _f	—	0.6	1	pF	V = 0, f = 1MHz
	Cut-off Frequency	f _c	15	80	—	kHz	V _{CE} = 5V, I _C = 2mA R _L = 100 Ω, -3dB
	Response Time (Rise)	t _r	—	4	18	μs	V _{CE} = 2V, I _C = 2mA
	Response Time (Fall)	t _f	—	3	18	μs	R _L = 100 Ω

$$*CTR = \frac{I_C}{I_F} \times 100\%$$

Typical Electrical/Optical Characteristic Curves
(25°C Ambient Temperature Unless Otherwise Noted)

Fig.1 Forward Current vs.
Ambient Temperature

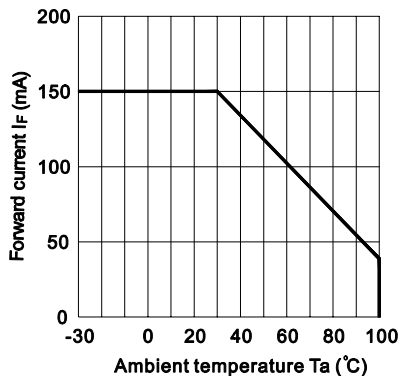


Fig.2 Collector Power Dissipation vs.
Ambient Temperature

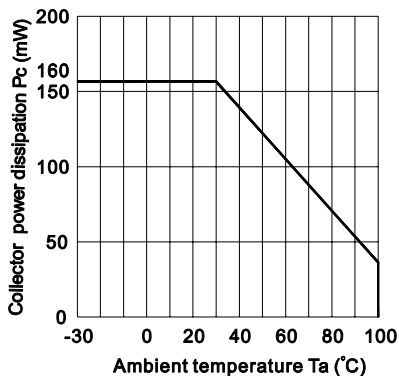


Fig.3 Collector-emitter saturation
Voltage vs. Forward current

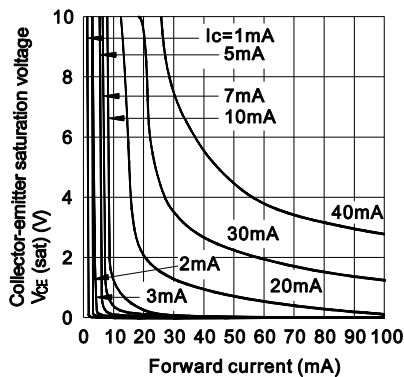


Fig.4 Forward Current vs. Forward
Voltage

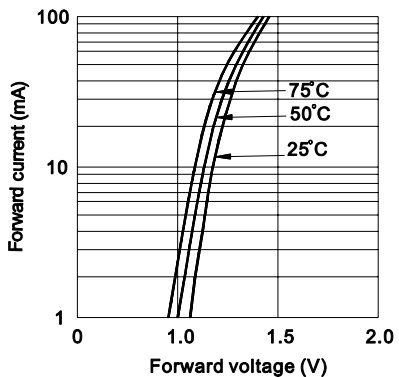


Fig.5 Current Transfer Ratio vs. Forward
Current

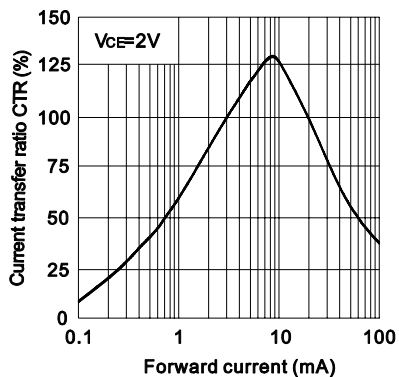


Fig.6 Collector Current vs.
Collector-emitter Voltage

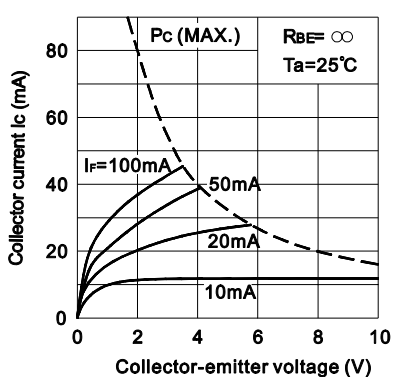


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

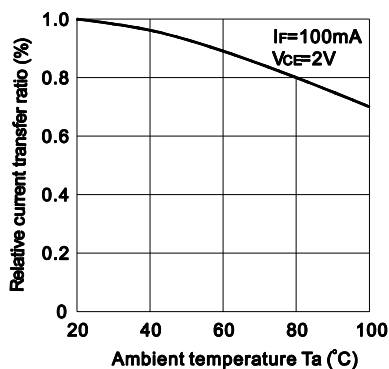


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

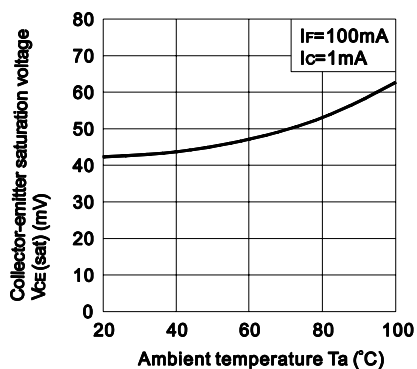


Fig.9 Collector Dark Current vs. Temperature

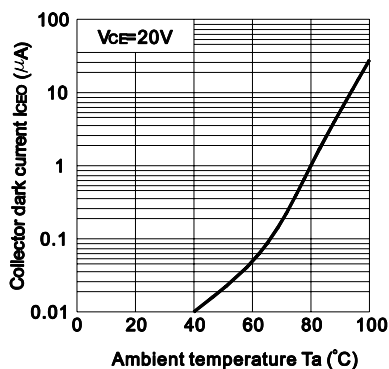


Fig.10 ICBO vs. Temperature

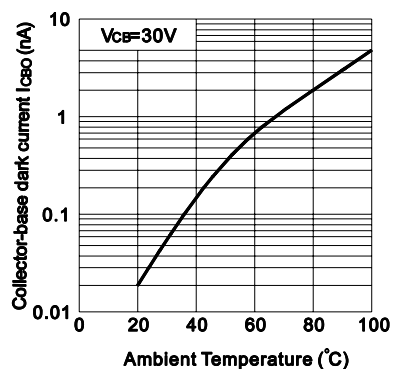


Fig.11 Response Time vs. Load Resistance

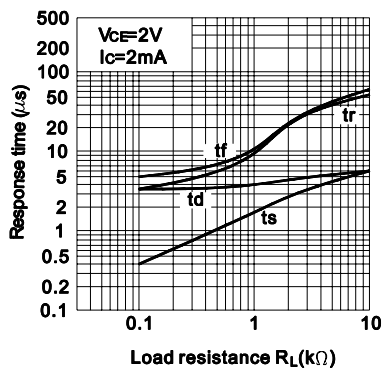


Fig.12 Frequency Response

